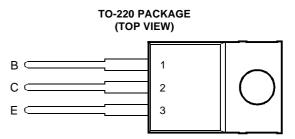
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- Designed for Complementary Use with the TIP31 Series
- 40 W at 25°C Case Temperature
- 3 A Continuous Collector Current
- 5 A Peak Collector Current
- Customer-Specified Selections Available



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT	
	TIP32		-80	
Collector-base voltage (I _E = 0)	TIP32A	V	-100	V
	TIP32B	V _{CBO}	-120	v
	TIP32C		-140	
	TIP32	5	-40	
Collector emitter voltage $(I_{-} 0)$	TIP 3 2A		-60	V
Collector-emitter voltage ($I_B = 0$)	TIP32B	VCEO	-80	
	TIP32C		-100	
Emitter-base voltage	10	V _{EBO}	-5	V
Continuous collector current	C	Ι _C	-3	А
Peak collector current (see Note 1)		I _{CM}	-5	А
Continuous base current		Ι _Β	-1	А
Continuous device dissipation at (or below) 25°C case temperature (see Note	2)	P _{tot}	40	W
Continuous device dissipation at (or below) 25°C free air temperature (see No	te 3)	P _{tot}	2	W
Unclamped inductive load energy (see Note 4)		½LI _C ²	32	mJ
Operating junction temperature range		Тj	-65 to +150	°C
Storage temperature range		T _{stg}	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds		ΤL	250	°C

NOTES: 1. This value applies for $t_p \le 0.3$ ms, duty cycle $\le 10\%$.

2. Derate linearly to 150°C case temperature at the rate of 0.32 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = -0.4 A, R_{BE} = 100 Ω , $V_{BE(off)}$ = 0, R_S = 0.1 Ω , V_{CC} = -20 V.

PRODUCT INFORMATION

Information is current as of publication date. Products conform to specifications in accordance with the terms of Power Innovations standard warranty. Production processing does not necessarily include testing of all parameters.



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electrical characteristics at 25°C case temperature

PARAMETER			TEST CONDI	TIONS	MIN			UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage			TIP32	-40			
		1 20 m 4	I _B = 0	TIP32A	-60			V
		I _C = -30 mA (see Note 5)		TIP32B	-80			
		(see note 5)		TIP32C	-100			
		V _{CE} = -80 V	$V_{BE} = 0$	TIP32			-0.2	
I _{CES}	Collector-emitter cut-off current	V _{CE} = -100 V	$V_{BE} = 0$	TIP32A			-0.2	mA
		V _{CE} = -120 V	$V_{BE} = 0$	TIP32B			-0.2	ШA
		V _{CE} = -140 V	$V_{BE} = 0$	TIP32C			-0.2	
I _{CEO}	Collector cut-off	V _{CE} = -30 V	I _B = 0	TIP32/32A			-0.3	mA
	current	V _{CE} = -60 V	$I_B = 0$	TIP32B/32C			-0.3	ШA
I _{EBO}	Emitter cut-off	V _{EB} = -5 V	I _C = 0				-1	mA
'EBO	current	VEB - OV						III.
h _{FE}	Forward current	$V_{CE} = -4 V$	I _C = -1 A	(see Notes 5 and 6)	25			
	transfer ratio	$V_{CE} = -4 V$	I _C = -3 A		10		50	
V _{CE(sat)}	Collector-emitter	I _B = -375 mA	I _C = -3 A	(see Notes 5 and 6)			-1.2	V
· CE(Sal)	saturation voltage	-B		(000 1000 0 0.00 0)				
V _{BE}	Base-emitter	V _{CE} = -4 V	I _C = -3 A	(see Notes 5 and 6)			-1.8	V
- DE	voltage		0				_	
h _{fe}	Small signal forward	V _{CE} = -10 V	I _C = -0.5 A	f = 1 kHz	20			
10	current transfer ratio		0		-			
h _{fe}	Small signal forward	V _{CE} = -10 V	I _C = -0.5 A	f = 1 MHz	3			
I' 'TEI	current transfer ratio		0 00000	40 3	-			

NOTES: 5. These parameters must be measured using pulse techniques, $t_p = 300 \ \mu s$, duty cycle $\leq 2\%$.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER			MAX	UNIT
R _{eJC} Junction to case thermal resistance			3.125	°C/W
R _{0JA} Junction to free air thermal resistance			62.5	°C/W

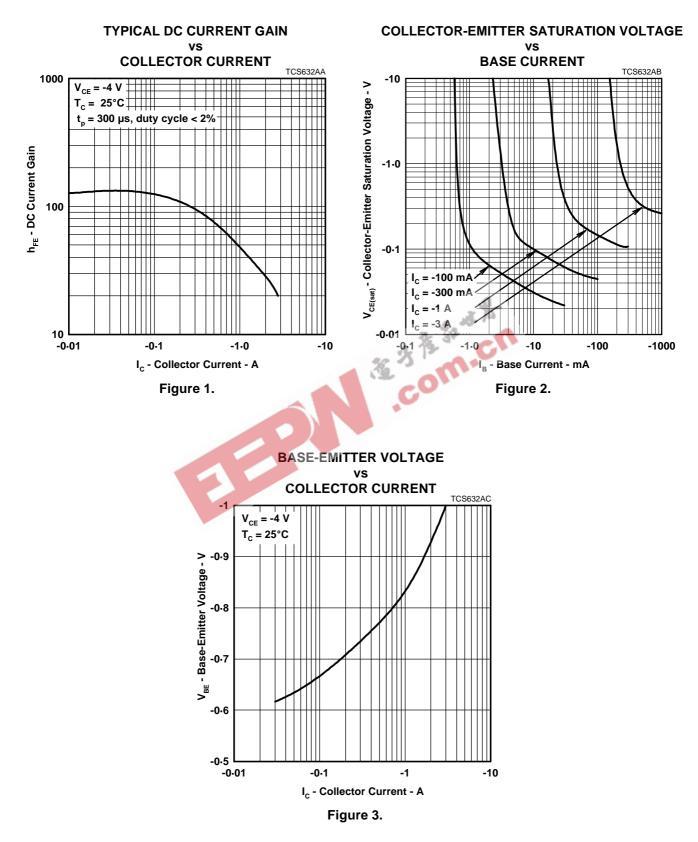
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resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS [†]			MIN	ТҮР	MAX	UNIT
t _{on}	Turn-on time	I _C = -1 A	I _{B(on)} = -0.1 A	$I_{B(off)} = 0.1 A$		0.3		μs
t _{off}	Turn-off time	$V_{BE(off)} = 4.3 V$	$R_L = 30 \ \Omega$	t_p = 20 µs, dc \leq 2%		1		μs

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

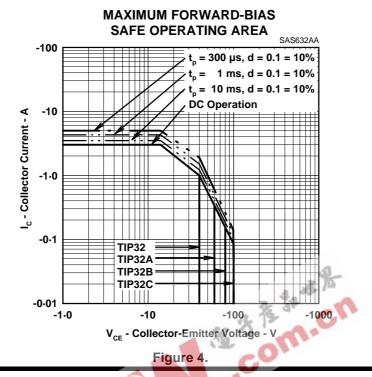
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TYPICAL CHARACTERISTICS

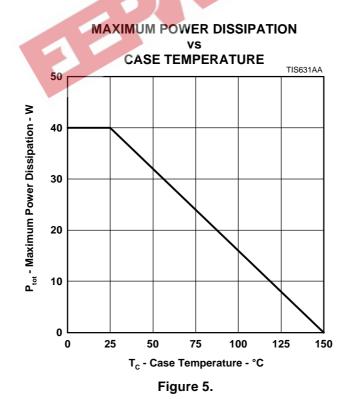


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MAXIMUM SAFE OPERATING REGIONS

THERMAL INFORMATION



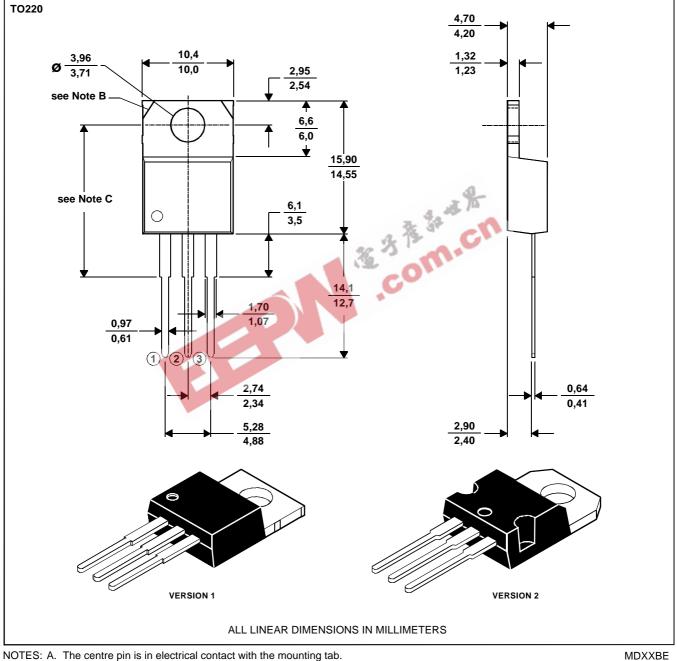
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MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



B. Mounting tab corner profile according to package version.

C. Typical fixing hole centre stand off height according to package version.

Version 1, 18.0 mm. Version 2, 17.6 mm.

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